

MACON

3.5-6.0 GHz Phase Shifter

MAPCGM0002-DIE

RO-P-DS-3050 A Preliminary Information

Features

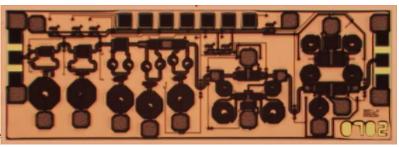
- 6 Bit Phase Shifter
- ♦ 360° Coverage, LSB = 5.6°
- ◆ TTL Control Inputs
- MSAG™ Process

Description

The MAPCGM0002-Die is a 6-bit Phase Shifter with Parallel TTL Input Control. This product is fully matched to 50 ohms on both the input and output. The part has 360° of phase coverage with LSB of 5.6°.

Fabricated using M/A-COM's repeatable, high performance and highly reliable GaAs Multifunction Self-Aligned Gate MESFET Process, each device is 100% RF tested on wafer to ensure performance compliance.

M/A-COM's MSAG™ process features robust silicon-like manufacturing processes, planar processing of ion implanted transistors, multiple implant capability enabling power, low-noise, switch and digital FETs on a single chip, and polyimide scratch protection for ease of use with automated manufacturing processes. The use of refractory metals and the absence of platinum in the gate metal formulation prevents hydrogen poisoning when employed in hermetic packaging.



Primary Applications

- Satellite Communication
- Phased Array Radar

Electrical Characteristics: $T_B = 40^{\circ}C^1$, $Z_0 = 50\Omega$, $V_{EE} = -5V$

Parameter	Symbol	Typical	Units
Bandwidth	f	3.5 - 6.0	GHz
Insertion Loss, Reference State	IL	6	dB
Input VSWR, All States	VSWR	1.5:1	
Output VSWR, All States	VSWR	1.7:1	
RMS Phase Error	Фкмѕ	8	0
RMS Phase Error, Calibrated	Фкмѕ	3	0
Peak to Peak Gain Variation, All States	ΔG	< 3	dB
Current	I _{EE}	< 10	mA
Input Third Order Intercept	ITOI	32	dBm
Input 1-dB Compression Point	P1dB	26	dBm

1. T_B = MMIC Base Temperature

- M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

information.





MAPCGM0002-DIE RO-P-DS-3050 A **Preliminary Information**

Maximum Operating Conditions ¹

Parameter	Symbol	Absolute Maximum	Units
Input Power	P _{IN}	31	dBm
Source Supply Voltage	V _{EE}	-6.0	V
Junction Temperature	T _J	180	°C
Storage Temperature	T _{STG}	-55 to +150	°C

^{1.} Operation outside of these ranges may reduce product reliability. Operation at other than the typical values may result in performance outside the guaranteed limits.

Recommended Operating Conditions

Characteristic	Symbol	Min	Тур	Max	Unit
Source Voltage	V_{EE}	-5.2	-5	-4.8	V
Control Voltage	V control pads				
Logic High		3	5	5	V
Logic Low		0	0	0.4	V

Operating Instructions

This device is static and light sensitive. Digital circuit operation can be impaired under high intensity light, e.g. microscope light. Please handle with care. To operate the device, follow these steps.

- 1. Power Up: Apply $V_{EE} = -5 \text{ V}$.
- 2. Apply Logic Voltages to control Circuits as listed in Recommended Operating Conditions
- 3. Power Down: Set $V_{EE} = 0$



- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0002-DIE RO-P-DS-3050 A **Preliminary Information**

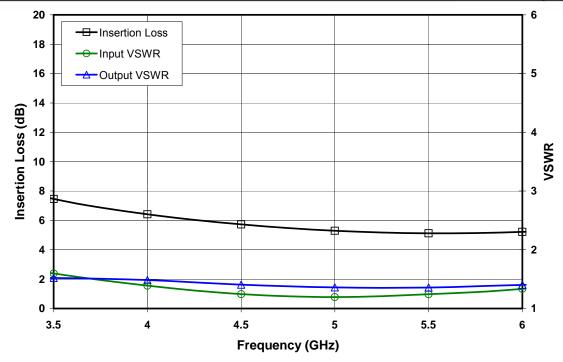


Figure 1. Reference State Insertion Loss, Input and Output VSWR vs. Frequency

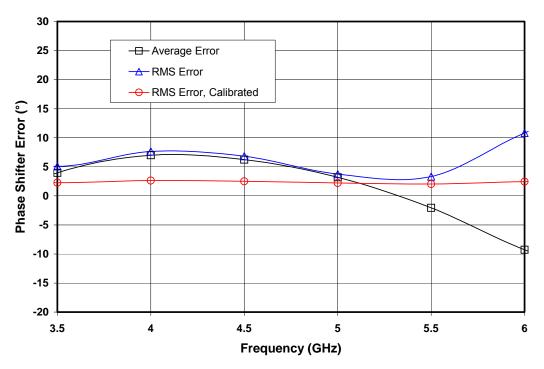


Figure 2. Phase Shifter Figures of Merit: Average Error vs Reference State, **RMS Error and Calibrated RMS Error over All States**

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298

MAPCGM0002-DIE RO-P-DS-3050 A Preliminary Information

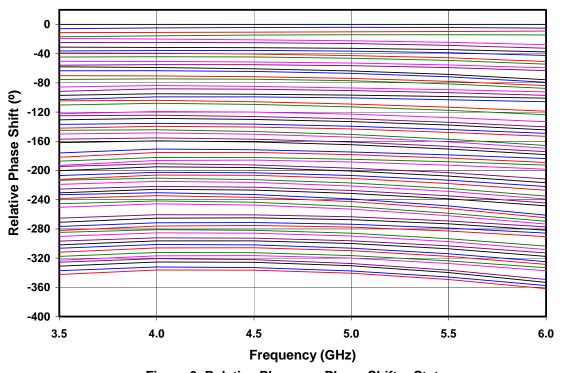


Figure 3. Relative Phase vs. Phase Shifter State

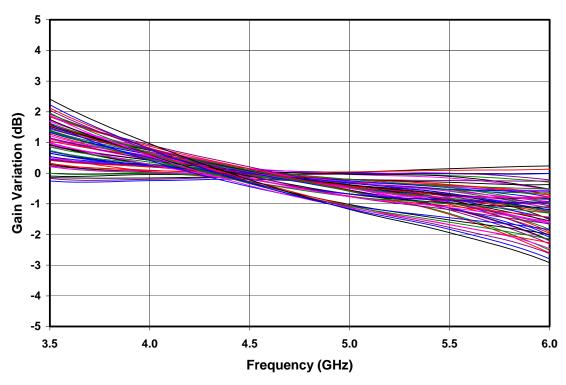


Figure 4. Relative Gain Change vs. Phase Shifter State

M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.

[•] North America Tel: 800.366.2266 / Fax: 978.366.2266

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0002-DIE RO-P-DS-3050 A **Preliminary Information**

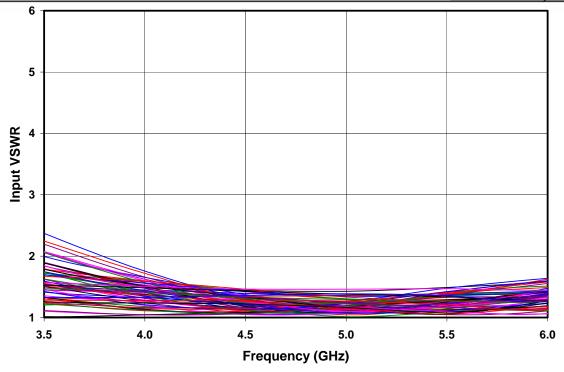


Figure 5. Input VSWR vs. Phase Shifter State

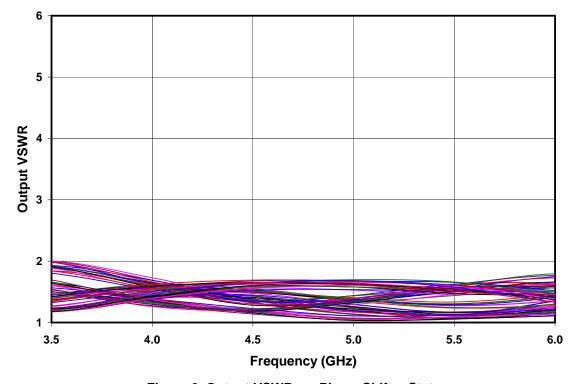


Figure 6. Output VSWR vs. Phase Shifter State

- M/A-COM Inc. and its affiliates reserve the right to make changes to the product(s) or information contained herein without notice. M/A-COM makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does M/A-COM assume any liability whatsoever arising out of the use or application of any product(s) or information.
- North America Tel: 800.366.2266 / Fax: 978.366.2266
- Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300
- Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298







MAPCGM0002-DIE RO-P-DS-3050 A Preliminary Information

Mechanical Information

Chip Size: 3.816 x 1.354 x 0.075 mm (150 x 53 x 3 mils)

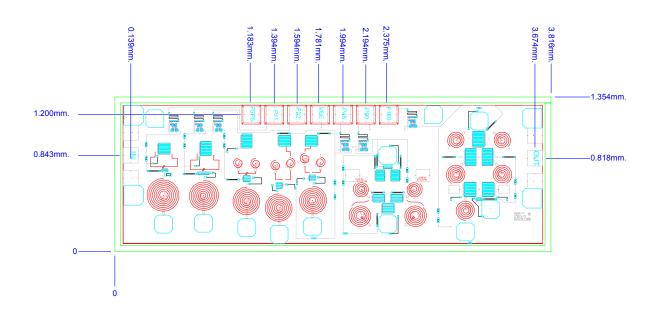


Figure 7. Die Layout

Bond Pad Dimensions

Pad	Size (μm)	Size (mils)
RF In and Out	100 x 200	4 x 8
DC Supply Voltage VEE	125 x 125	5 x 5
DC Control Voltage VC	125 x 125	5 x 5

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298





MAPCGM0002-DIE RO-P-DS-3050 A

Preliminary Information

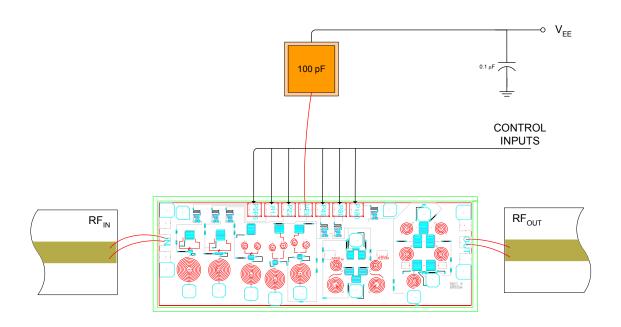


Figure 8. Recommended bonding diagram for pedestal mount. Support circuitry typical of MMIC characterization.

Assembly Instructions:

Die attach: Low thermal conductivity silver epoxies are acceptable for die attach of this MMIC. Follow the manufacturer's instructions. If solder is employed, use AuSn (80/20) 1-2 mil preform solder. Limit time @ 300 °C to less than 5 minutes.

Wirebonding: Bond @ 160 °C using standard ball or thermal compression wedge bond techniques. For DC and RF pad connections, use either ball or wedge bonds. For best performance, especially above 10 GHz, wedge bonds of shortest length employed on the RF interconnects is preferred over ball bonds.

[•] Europe Tel: 44.1908.574.200 / Fax: 44.1908.574.300

Asia/Pacific Tel: 81.44.844.8296 / Fax: 81.44.844.8298